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著者	Suzuki Shugo, Higai Shin'ichi, Nakao Kenji
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## Two-Dimensional $\sigma$ -Hole Systems in Boron Layers: A First-Principles Study on $Mg_{1-x}Na_xB_2$ and $Mg_{1-x}Al_xB_2$

Shugo Suzuki, Shin'ichi Higai<sup>1</sup> and Kenji Nakao

Institute of Materials Science, University of Tsukuba, Tsukuba 305-8573

<sup>1</sup> National Research Institute for Metals, 1-2-1 Sengen, Tsukuba 305-0047

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We study two-dimensional  $\sigma$ -hole systems in boron layers by calculating the electronic structures of  $\mathrm{Mg_{1-x}Na_xB_2}$  and  $\mathrm{Mg_{1-x}Al_xB_2}$ . In  $\mathrm{Mg_{1-x}Na_xB_2}$ , it is found that the concentration of  $\sigma$  holes is approximately described by  $(0.8+0.8x)\times 10^{22}~\mathrm{cm^{-3}}$  and the largest attainable concentration is about  $1.6\times 10^{22}~\mathrm{cm^{-3}}$  in  $\mathrm{NaB_2}$ . In  $\mathrm{Mg_{1-x}Al_xB_2}$ , on the other hand, it is found that the concentration of  $\sigma$  holes is approximately described by  $(0.8-1.4x)\times 10^{22}~\mathrm{cm^{-3}}$  and  $\sigma$  holes disappear at x of about 0.6. These relationships can be used for experimental studies on  $\sigma$ -hole systems in these materials.

KEYWORDS: MgB<sub>2</sub>, NaB<sub>2</sub>, AlB<sub>2</sub>, σ holes, two dimension, hole concentration

Recently, Nagamatsu et al. have discovered that magnesium diboride,  $MgB_2$ , is a superconductor with a high transition temperature,  $T_c$ , of 39 K.<sup>1)</sup> Extensive studies have now started both experimentally and theoretically. In particular, since  $MgB_2$  can be regarded as a starting material for undiscovered high- $T_c$  superconductors, it is important to search for various materials derived from  $MgB_2$ .

The structure of MgB<sub>2</sub> consists of layers of triangular lattices of Mg atoms and layers of honeycomb lattices of B atoms.<sup>2)</sup> This structure is basically the same as that of the alkali-metal binary graphite intercalation compounds (GIC).<sup>3)</sup> Since Mg and B are light elements, where the s and p atomic orbitals play dominant roles, the electronic structure of MgB<sub>2</sub><sup>4)</sup> is also very similar to those of GIC.<sup>5)</sup> In spite of these similarities, there are no GIC superconductors developed with such a high  $T_c$ ; the highest  $T_c$  of alkali-metal GIC is only about 0.15 K for C<sub>8</sub>K.<sup>6)</sup>

One significant difference between MgB<sub>2</sub> and GIC is the existence of the  $\sigma$  holes at the center of the Brillouin zone,<sup>4)</sup> which are derived from the  $2p_x$  and  $2p_y$  atomic orbitals of B. Since the  $\sigma$  bands in graphite layers are energetically very deep, the generation of  $\sigma$  holes is extremely difficult in GIC. Furthermore, it is interesting to note that holes in boron layers will show characteristics of two-dimensional (2D) systems. As revealed thus far, 2D systems can provide a rich variety of physics and possibilities of applications. It is thus important for understanding the properties of MgB<sub>2</sub> and its derivatives to study the electronic structures of the  $\sigma$ -hole systems in boron layers.

In this Letter, we study the 2D  $\sigma$ -hole systems in  $Mg_{1-x}Na_xB_2$  and  $Mg_{1-x}Al_xB_2$  at x=0, 1/3, 2/3, and 1 by calculating the electronic structures of these materials based on the density functional theory. The main results of the present study are as follows. In  $Mg_{1-x}Na_xB_2$ , since Na is a monovalent metal, the concentration of  $\sigma$  holes is increased with increasing x, approximately described by  $(0.8+0.8x)\times 10^{22} \text{cm}^{-3}$ . In  $Mg_{1-x}Al_xB_2$ , on the contrary, since Al is a trivalent metal, the concentration of  $\sigma$  holes is reduced with increasing x, approximately described by  $(0.8-1.4x)\times 10^{22} \text{cm}^{-3}$ . In the latter case, the  $\sigma$  holes disappear at x of about 0.6. These results can be used for experimental studies on  $\sigma$ -hole systems in these materials.

In the present study, we carry out first-principles calculations based on the density functional theory with the local density approximation<sup>7–10)</sup> by considering all electrons. To confirm the reliability of the results, the Kohn-Sham equations are solved using both the mixed-basis method and the linear-combination-of-atomic-orbital (LCAO) method.<sup>11)</sup> In this paper, we present the results obtained using the mixed-basis method although the same results can also be obtained using the LCAO method. The cut-off energy used for plane waves is 50 eV and the atomic orbitals employed as localized orbitals are given in Table I. We use not only the atomic orbitals of neutral atoms but also those of charged atoms to increase the variational flexibility. The number of used k points in the full Brillouin zone is 52 for the structure optimization of NaB<sub>2</sub> and 185 for the electronic structure calculations of NaB<sub>2</sub>, MgB<sub>2</sub>, and AlB<sub>2</sub>. Moreover, that used in the calculations of Mg<sub>1-x</sub>Na<sub>x</sub>B<sub>2</sub> and Mg<sub>1-x</sub>Al<sub>x</sub>B<sub>2</sub> is 104.

We first calculate the electronic structures of NaB<sub>2</sub>, MgB<sub>2</sub>, and AlB<sub>2</sub>. The calculations are performed using the experimental lattice constants of MgB<sub>2</sub> and AlB<sub>2</sub>; a = 3.084 Å and c = 3.522 Å are used for MgB<sub>2</sub> and a = 3.009 Å and c = 3.262 Å are used for AlB<sub>2</sub>. On the other hand, since NaB<sub>2</sub> is a hypothetical material at present, it is necessary to optimize the lattice constants of this material. The resultant constants a and c are 3.02 Å and 4.19 Å, respectively, and are used for NaB<sub>2</sub>. To confirm the reliability of this result, we also optimize the structure of MgB<sub>2</sub> and find that the errors for a and c are -2 % and +0.5 %, respectively. We thus believe that the result for NaB<sub>2</sub> is also reliable with the same accuracy. The lattice constants c of these materials can be understood by considering the fact that the ionic radii of Na<sup>+</sup>, Mg<sup>2+</sup>, and Al<sup>3+</sup> are 0.97 Å, 0.65 Å, and 0.50 Å, respectively.

In Figs. 1(a), 1(b), and 1(c), the calculated electronic structures of NaB<sub>2</sub>, MgB<sub>2</sub>, and AlB<sub>2</sub> are shown, respectively. The dotted lines in the figures indicate the Fermi level. The most impressive point is the position of the top of the  $\sigma$  bands derived from the  $2p_x$  and  $2p_y$  atomic orbitals of B. In NaB<sub>2</sub> and MgB<sub>2</sub>, the top of the  $\sigma$  bands is above the Fermi level, and accordingly, there exist  $\sigma$  holes in these materials. This is in strong contrast to the fact that there are no  $\sigma$  holes in GIC. Since Na is a monovalent metal while Mg is a divalent metal, the concentration of  $\sigma$  holes is higher in NaB<sub>2</sub> than in MgB<sub>2</sub>. Thus, the concentration of the  $\sigma$  holes can be increased when we increase

x in  $Mg_{1-x}Na_xB_2$ . On the contrary, in  $AlB_2$ , the top of the  $\sigma$  bands is below the Fermi level and accordingly there are no  $\sigma$  holes in this material. Thus, the concentration of  $\sigma$  holes is reduced when we increase x in  $Mg_{1-x}Al_xB_2$ , and eventually they disappear at a certain value of x.

Furthermore, since the dispersion of the top of the  $\sigma$  bands of all the materials is very small along the  $\Gamma$ -A direction, the  $\sigma$  holes can exhibit characteristics of 2D systems such as large fluctuation. This is in strong contrast to the three-dimensionality of other carriers in these materials. In all the materials studied, there exist three-dimensional (3D)  $\pi$  electrons and/or holes. Moreover, in AlB<sub>2</sub>, there exist a small number of 3D electrons in the nearly free electron state at the  $\Gamma$  point, which is derived from the hybridization between the 3s atomic orbitals of Al and the interlayer state of boron layers; this is very similar to the situation in C<sub>8</sub>K, where the nearly free electrons also exist at the  $\Gamma$  point.<sup>12)</sup> It should be noted that, in GIC, there exist  $\pi$  electrons and/or holes and also nearly free electrons and not  $\sigma$  holes.

Next, we study the electronic structures of  $Mg_{1-x}Na_xB_2$  and  $Mg_{1-x}Al_xB_2$  at x=0, 1/3, 2/3, and 1. In the calculations, we assume an in-plane  $(\sqrt{3} \times \sqrt{3})$  structure, as shown in Fig. 2. This structure is simple because the threefold rotation axis also exists as in the  $(1 \times 1)$  original structure, and thus, the same Brillouin zone can be used. We also assume that the lattice constants of these materials can be obtained by linearly interpolating between the lattice constants of  $MgB_2$  and  $NaB_2$  or  $AlB_2$ . As an example, we show the result for  $Mg_{2/3}Na_{1/3}B_2$  in Fig. 3. The obtained electronic structure can be understood by considering the folding of the original band structures shown in Fig. 1. The  $\sigma$  bands are easily identified to be the bands with small dispersion along the  $\Gamma$ -A direction immediately above the Fermi level.

In Fig. 4, we show the top of the  $\sigma$  bands in  $\mathrm{Mg}_{1-x}\mathrm{Na}_x\mathrm{B}_2$  and  $\mathrm{Mg}_{1-x}\mathrm{Al}_x\mathrm{B}_2$  as a function of x. The dotted line in the figure indicates the Fermi level. It is found that the dependence is monotonic and the largest attainable value is 1.8 eV for  $\mathrm{NaB}_2$ . We also find that, in  $\mathrm{Mg}_{1-x}\mathrm{Al}_x\mathrm{B}_2$ , the top of the  $\sigma$  bands is below the Fermi level for x larger than about 0.6, that is, the  $\sigma$  holes disappear for such x. The dependence on x for the entire region from  $\mathrm{NaB}_2$  to  $\mathrm{AlB}_2$  via  $\mathrm{MgB}_2$  shown in Fig. 4 cannot be fitted with a single straight line. It is necessary to fit the result with a curve or, at least, with two straight lines, one for  $\mathrm{Mg}_{1-x}\mathrm{Na}_x\mathrm{B}_2$  and the other for  $\mathrm{Mg}_{1-x}\mathrm{Al}_x\mathrm{B}_2$ . If we select the latter choice, the result can be fitted with

$$\varepsilon_{\text{top}} = 0.90 + 0.91x \text{ eV} \tag{0.1}$$

for  $Mg_{1-x}Na_xB_2$  and with

$$\varepsilon_{\text{top}} = 0.90 - 1.57x \text{ eV} \tag{0.2}$$

for  $Mg_{1-x}Al_xB_2$ . Here, we ignore the point for  $AlB_2$  in obtaining the above formulae because some quantities, including the top of the  $\sigma$  bands and the cohesive energy as shown below, are not on

the same straight line as the other  $Mg_{1-x}Al_xB_2$ ; this can be ascribed to the existence of the nearly free electrons in  $AlB_2$  which do not exist in the other  $Mg_{1-x}Al_xB_2$  calculated in the present study.

In Fig. 5, we show the cohesive energy of  $Mg_{1-x}Na_xB_2$  and  $Mg_{1-x}Al_xB_2$  as a function of x. It is found that the most stable material is  $AlB_2$  and the least stable one is  $NaB_2$ . The dependence on x for the entire region from  $NaB_2$  to  $AlB_2$  via  $MgB_2$  can be described by a single straight line if we ignore the point for  $AlB_2$  because the cohesive energy may be affected by the existence of the nearly free electrons as mentioned above. The result can be fitted with

$$E_{\rm c} = 5.59 - 0.62x \, \text{eV/atom}$$
 (0.3)

for  $Mg_{1-x}Na_xB_2$  and with

$$E_{\rm c} = 5.59 + 0.62x \,\text{eV/atom}$$
 (0.4)

for  $Mg_{1-x}Al_xB_2$ . Although  $NaB_2$  is a hypothetical material at present, we believe that this material can be synthesized under some appropriate conditions because the cohesive energy of  $NaB_2$ , about 5 eV/atom, is not very small; it is almost the same as that of the bulk Si.

Next, we study the dependence of the concentration of  $\sigma$  holes on x by assuming a constant density of states for the upper region of the  $\sigma$  bands. This assumption is good as long as two conditions are satisfied; one is that the dispersion along the  $\Gamma$ -A direction is very small and the other is that the deviation from the in-plane free-electron-like dispersion is negligible. Since both conditions are satisfied as shown in Fig. 1, we derive the formulae which give the concentration of  $\sigma$  holes for a given x. First, it is necessary to fit the in-plane free-electron-like dispersion using effective masses for heavy and light holes. As a result, we find that the effective mass for heavy holes is  $0.5m_{\rm e}$  and that for light holes is  $0.3m_{\rm e}$ , where  $m_{\rm e}$  is the mass of free electrons. Next, by combining these results with those shown in Fig. 4, the following formulae are derived to determine the concentration of the  $\sigma$  holes:

$$n_{\rm h} = (0.8 + 0.8x) \times 10^{22} \,{\rm cm}^{-3}$$
 (0.5)

or

$$n_{\rm h} = 0.12 + 0.12x / \text{B atom}$$
 (0.6)

for  $Mg_{1-x}Na_xB_2$  and

$$n_{\rm h} = (0.8 - 1.4x) \times 10^{22} \,{\rm cm}^{-3}$$
 (0.7)

or

$$n_{\rm h} = 0.12 - 0.21x / \text{B atom}$$
 (0.8)

for  $Mg_{1-x}Al_xB_2$ . Thus, in  $Mg_{1-x}Na_xB_2$ , the largest attainable concentration of  $\sigma$  holes is about  $1.6 \times 10^{22}$  cm<sup>-3</sup> in  $NaB_2$ . In  $Mg_{1-x}Al_xB_2$ , on the other hand,  $\sigma$  holes disappear at x of about 0.6. Here, we discuss the possibility of LiB<sub>2</sub> as a candidate for increasing the concentration of  $\sigma$  holes. Although one may expect that LiB<sub>2</sub> is the most plausible candidate because of the almost same in the relation of  $I_1$  and  $I_2$  this group at the theorem. We have found that the

Although one may expect that LiB<sub>2</sub> is the most plausible candidate because of the almost same ionic radius of Li<sup>+</sup>, 0.68 Å, as that of Mg<sup>2+</sup>, this may not be the case. We have found that the structure optimization of LiB<sub>2</sub> results in strong contraction of c, which is found to be less than 3 Å. The result strongly conflicts with a simple expectation that the lattice constant c of LiB<sub>2</sub> should be about 3.6 Å if we estimate it by considering the ionic radius of Li<sup>+</sup>. To elucidate the stable structure of LiB<sub>2</sub>, our study on this is now in progress. In spite of this result, one can still expect that Mg<sub>1-x</sub>Li<sub>x</sub>B<sub>2</sub> for sufficiently small x can be synthesized because the introduction of sufficiently small Li cannot affect the lattice constant c very strongly.

We next discuss the difference between MgB<sub>2</sub> and other metal diborides such as transition-metal (TM) diborides<sup>13)</sup> and noble-metal diborides, AgB<sub>2</sub> and AuB<sub>2</sub>. The most important point is the absence of d atomic orbitals in MgB<sub>2</sub> in contrast to the existence of d atomic orbitals in other metal diborides. In particular, since the d atomic orbitals in TM are partly filled, they form strong covalent bonding with  $\sigma$  bonds of boron layers. This can destroy a 2D  $\sigma$ -hole system in boron layers; we have calculated the electronic structures of some TM diborides and have found that the  $\sigma$  bands of boron layers are strongly affected by the covalent bonding with d atomic orbitals of TM. On the other hand, AgB<sub>2</sub> and AuB<sub>2</sub> can be candidates for materials similar to MgB<sub>2</sub>. The reason for this is that the  $\sigma$  holes may survive in these materials because d atomic orbitals in these materials should be sufficiently lower than the Fermi level, and thus, the hybridization between the d atomic orbitals and the  $\sigma$  bands may occur at a lower-energy region.

We finally discuss the possible relationship between the superconductivity in MgB<sub>2</sub> and the 2D  $\sigma$ -hole systems in boron layers. If the superconductivity in Mg<sub>1-x</sub>Al<sub>x</sub>B<sub>2</sub> disappears at x of about 0.6, it should be caused by the  $\sigma$ -hole systems. In addition, there are no TM diborides with  $T_c$  as high as that of MgB<sub>2</sub>; this may be due to the fact that they have no  $\sigma$  holes. If this is the case, both the electron-phonon interaction and the electron correlation may be the likely origins of the superconductivity. Since  $\sigma$  bonds, particularly those of B, C, N, and O, are very strong, the interaction between the  $\sigma$  holes and the in-plane  $\sigma$ -bond vibration is also expected to be very strong. Furthermore, this electron-phonon coupling can result in a superconductivity of high  $T_c$  because the frequency of the  $\sigma$ -bond vibration is of the order of 0.2 eV. On the other hand, the electron correlation in the  $\sigma$  holes appears also important for the properties of the  $\sigma$ -hole system in MgB<sub>2</sub> because the wave function of the  $\sigma$  holes is localized to a considerable degree.

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### **Figure Captions**

Fig. 1. Band structures of (a) NaB<sub>2</sub>, (b) MgB<sub>2</sub>, and (c) AlB<sub>2</sub>. The dotted lines indicate the Fermi level.

Fig. 2. In-plane  $(\sqrt{3} \times \sqrt{3})$  structure (dashed lines) used in the electronic structure calculations of  $Mg_{1-x}M_xB_2$ (M=Na or Al, x=0, 1/3, 2/3, and 1) and original  $(1 \times 1)$  structure (dotted lines). Small closed circles represent B atoms and large circles represent the other atoms. For x=0, all the large circles are Mg atoms. For x=1/3, open and hatched circles are Mg and M atoms, respectively. For x=2/3, open and hatched circles are M and Mg, respectively. For x=1, all the large circles are M atoms. Fig. 3. Band structure of Mg<sub>2/3</sub>Na<sub>1/3</sub>B<sub>2</sub>. The dotted lines indicate the Fermi level. Fig. 4. Top of the  $\sigma$  bands as a function of x. The horizontal axis is from NaB<sub>2</sub> to AlB<sub>2</sub> via MgB<sub>2</sub>. The dotted line indicates the Fermi level. The solid line fits the four points for  $Mg_{1-x}Na_xB_2$ . The dotted-dashed line fits the three points for  $Mg_{1-x}Al_xB_2$ , ignoring the point for  $AlB_2$ . Fig. 5. Cohesive energy as a function of x. The horizontal axis is from NaB<sub>2</sub> to AlB<sub>2</sub> via MgB<sub>2</sub>. The solid line fits the six points for  $Mg_{1-x}Na_xB_2$  and  $Mg_{1-x}Al_xB_2$ , ignoring the point for  $AlB_2$ .

 ${\it Table \ I.} \quad {\it Atomic \ orbitals \ used \ for \ mixed-basis \ calculations.}$ 

Atom	Atomic orbitals (atomic charge)
В	$1s, 2s, 2p  ext{(neutral)}$
Na	1s, 2s, 2p, 3s (neutral)
Mg	1s, 2s, 2p, 3s (neutral); $3p(1+)$ ; $3d(2+)$
Al	1s, 2s, 2p, 3s, 3p(neutral); $3d(2+)$

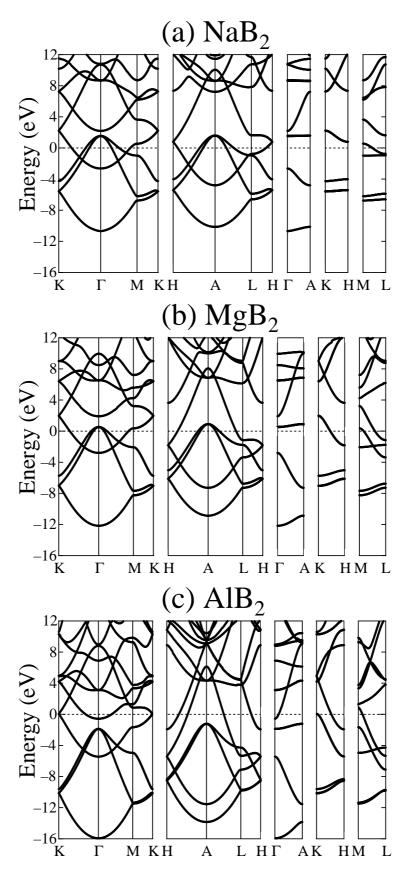


Fig. 1

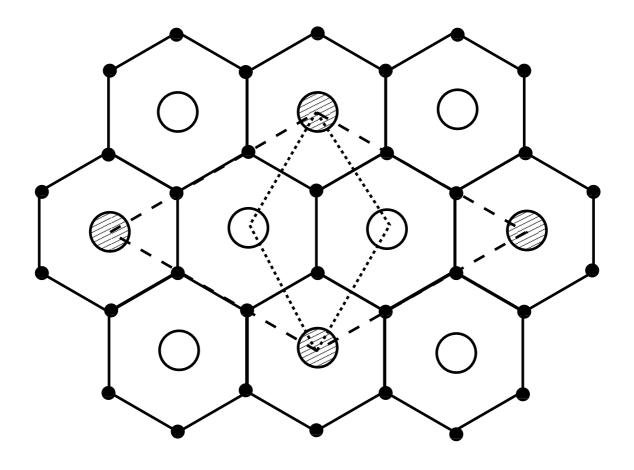


Fig. 2

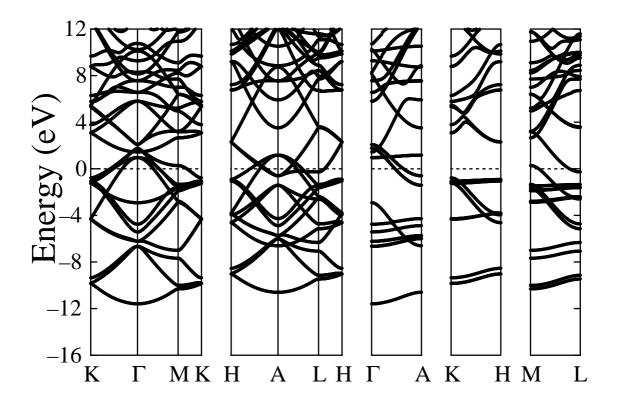


Fig. 3

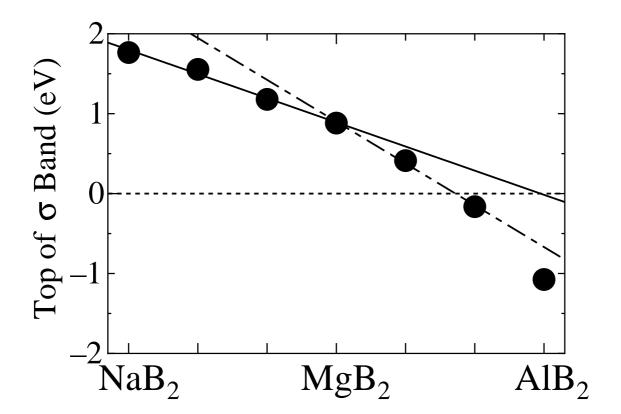


Fig. 4

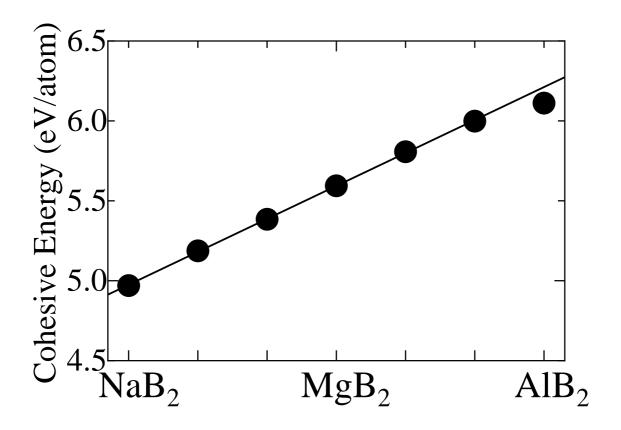


Fig. 5